

Supporting Information

Molecular Engineering of Simple Carbazole-Arylamine Hole-Transport Materials for Perovskite Solar Cells

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Table S1 The average photovoltaic parameters of n-i-p (FAPbI₃)_{0.85}(MAPbBr₃)_{0.15}-based PSCs with different additive-free HTMs.

HTM	Concentration n (mg mL ⁻¹)	V _{oc} (V)	J _{sc} (mA cm ⁻²)	FF (%)	PCE (%)
3,6-O	10	1.01 ± 0.02	17.12 ± 0.73	58 ± 1.94	10.10 ± 0.59
3,6-O	20	1.05 ± 0.01	19.20 ± 0.37	65 ± 1.07	13.23 ± 0.45
3,6-O	30	1.03 ± 0.01	18.69 ± 0.32	64 ± 0.87	12.43 ± 0.18
3,6-O	45	1.03 ± 0.01	18.21 ± 0.39	61 ± 0.79	11.49 ± 0.10
3,6-N	10	1.01 ± 0.02	18.71 ± 0.39	65 ± 0.87	12.48 ± 0.36
3,6-N	20	1.04 ± 0.01	20.09 ± 0.57	73 ± 1.87	15.28 ± 0.72
3,6-N	30	1.01 ± 0.02	16.82 ± 0.42	59 ± 0.79	10.06 ± 0.48
3,6-N	45	0.91 ± 0.03	15.24 ± 0.56	49 ± 1.62	6.82 ± 0.39
3,6-S	10	1.01 ± 0.02	17.75 ± 0.29	50 ± 1.90	10.70 ± 0.35
3,6-S	20	1.04 ± 0.01	20.14 ± 0.37	70 ± 0.89	14.73 ± 0.30
3,6-S	30	1.04 ± 0.01	19.67 ± 0.25	67 ± 0.62	13.74 ± 0.39
3,6-S	45	1.03 ± 0.01	18.91 ± 0.26	62 ± 0.77	12.11 ± 0.15
Spiro	20				
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OMeTAD		1.01 ± 0.01	19.95 ± 0.24	61 ± 0.68	12.68 ± 0.24

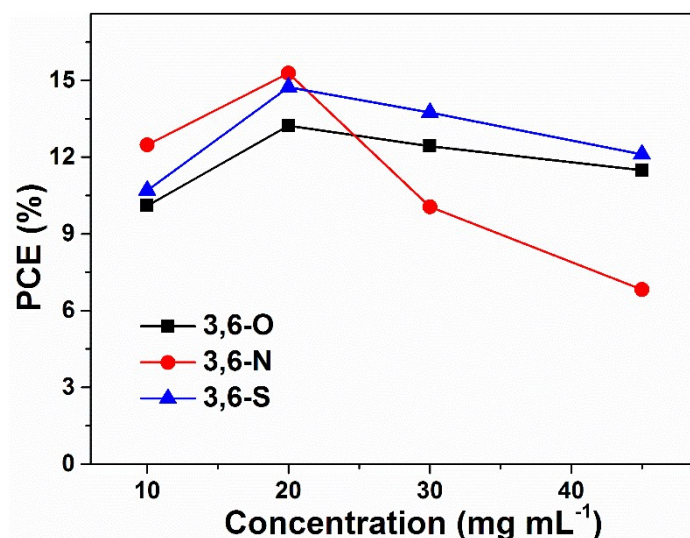
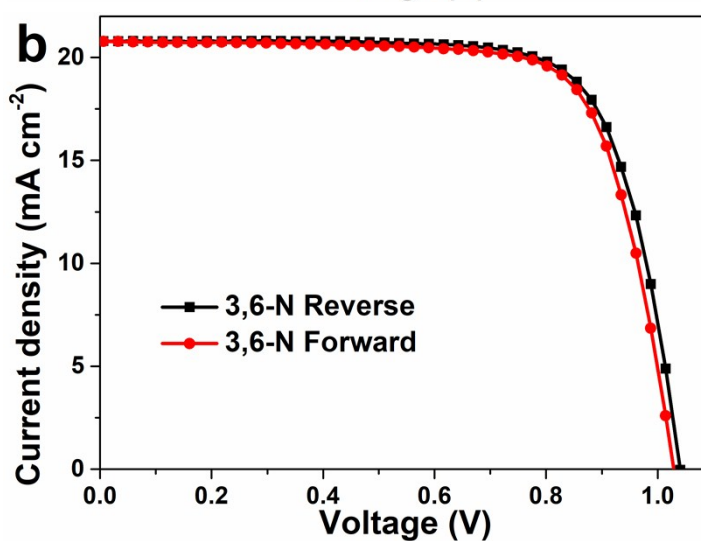
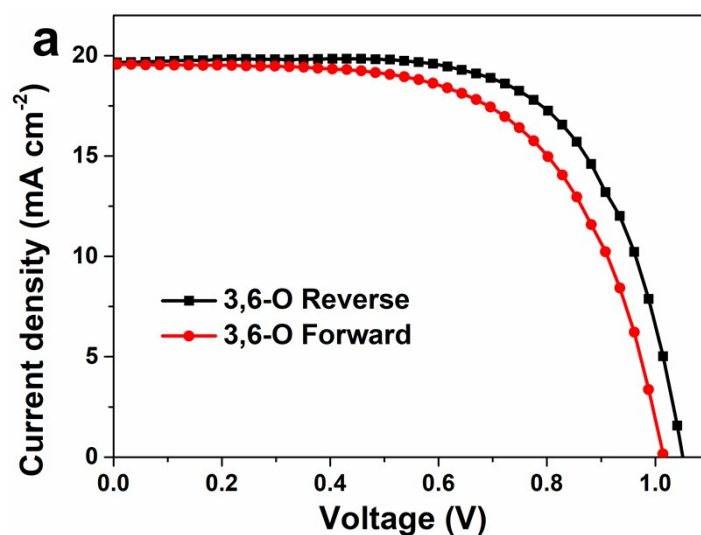


Fig. S1 The average PCE variations with the concentration change of additive-free 3,6-O, 3,6-N and 3,6-S for Table 1.



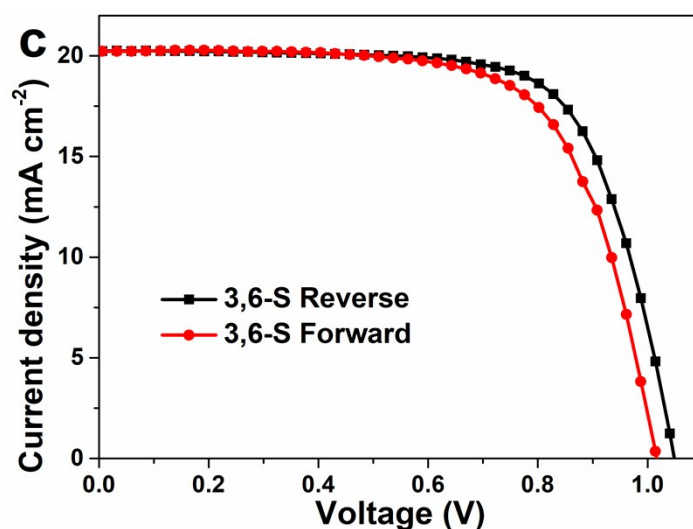


Fig. S2 *J-V* curves measured by forward scan (from short circuit to open circuit) and reverse scan (from open circuit to short circuit) of the n-i-p (FAPbI₃)_{0.85}(MAPbBr₃)_{0.15}-based PSCs with different additive-free HTMs under AM 1.5 illumination.

Table S2 Photovoltaic parameters of best-performing n-i-p (FAPbI₃)_{0.85}(MAPbBr₃)_{0.15}-based PSCs with different additive-free HTMs and measured through forward and reverse scans for Fig. S2.

HTM		V_{oc} (V)	J_{sc} (mA cm ⁻²)	FF (%)	PCE (%)
3,6-O	Reverse	1.05	19.71	67	13.84
	Forward	1.01	19.56	62	12.30
3,6-N	Reverse	1.04	20.80	74	16.12
	Forward	1.03	20.78	74	15.85
3,6-S	Reverse	1.05	20.24	71	15.01
	Forward	1.02	20.23	68	14.02

Table S3 The average photovoltaic parameters of n-i-p (FAPbI₃)_{0.85}(MAPbBr₃)_{0.15}-based PSCs with different doped HTMs (20 mg mL⁻¹).

HTM	V_{oc} (V)	J_{sc} (mA cm ⁻²)	FF (%)	PCE (%)
3,6-O	1.07 ± 0.02	21.87 ± 0.53	73 ± 1.13	17.04 ± 0.26

3,6-N	1.07 ± 0.01	22.06 ± 0.47	77 ± 1.85	18.21 ± 0.18
3,6-S	1.08 ± 0.01	22.04 ± 0.51	73 ± 0.98	17.37 ± 0.33

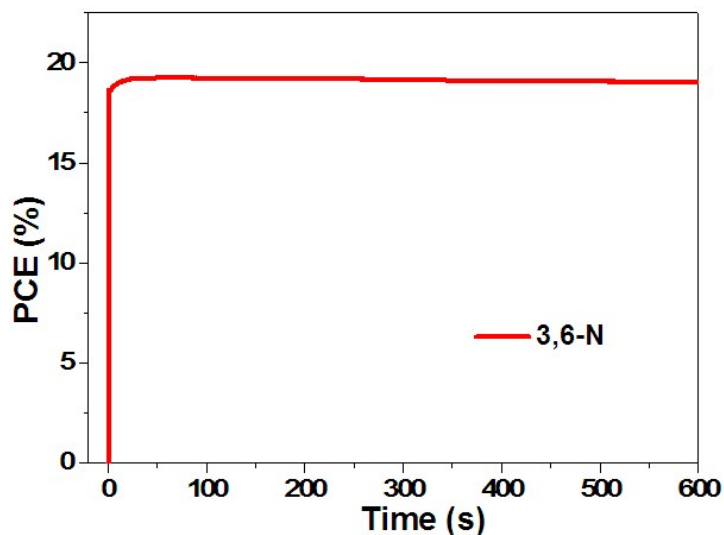


Fig. S3 The stabilized power output of the best-performing devices with doped 3,6-N, measured at 0.90 V.

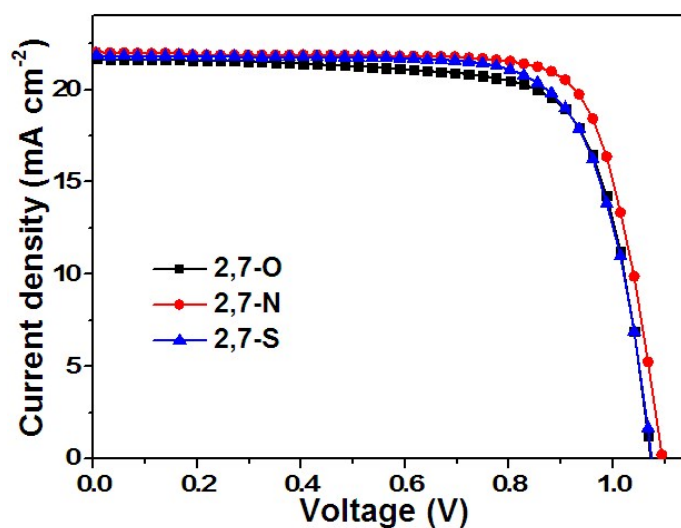


Fig. S4 *J-V* curves of best-performing n-i-p (FAPbI₃)_{0.85}(MAPbBr₃)_{0.15}-based PSCs with doped 2,7-HTMs.

Table S4 Photovoltaic parameters of the n-i-p (FAPbI₃)_{0.85}(MAPbBr₃)_{0.15}-based PSCs with doped 2,7-HTMs for Fig. S4.

HTM	V_{oc} (V)	J_{sc} (mA cm ⁻²)	FF (%)	PCE (%)	PCE_{avg}^a
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					(%)
2,7-O	1.07	21.67	74	17.27	15.84
2,7-N	1.09	22.01	77	18.65	16.17
2,7-S	1.07	21.85	74	17.48	15.92

^a Average PCE from 5 independent cells.

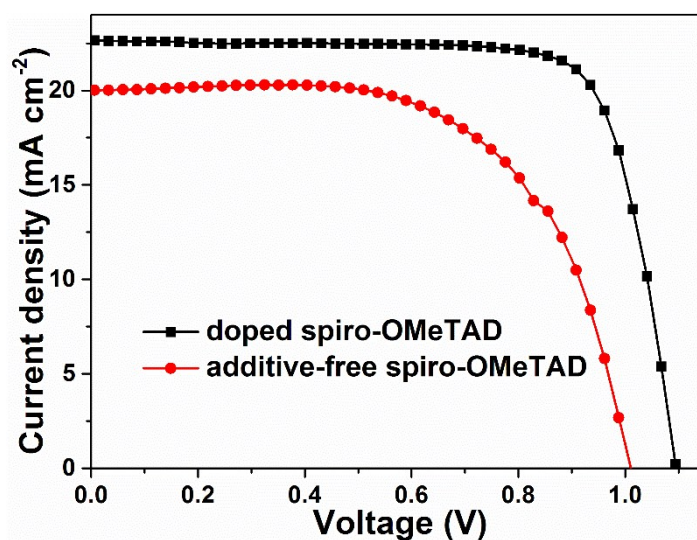
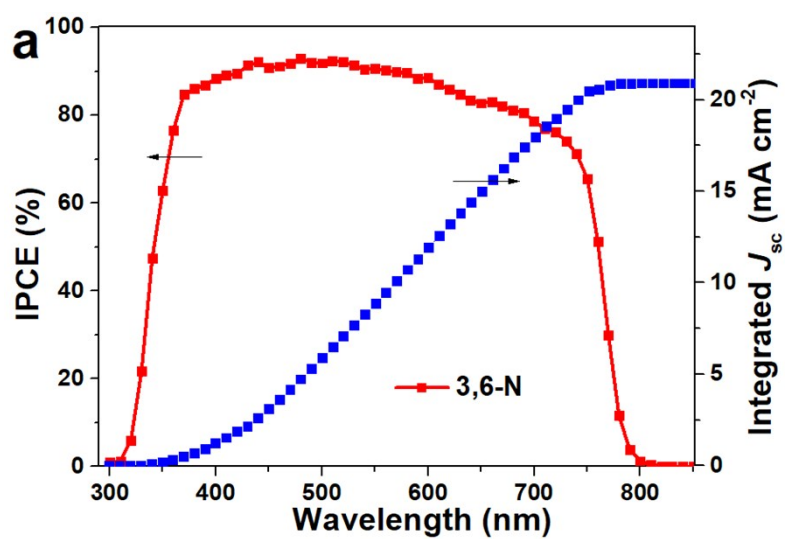


Fig. S5 *J-V* curves of the best-performing n-i-p (FAPbI₃)_{0.85}(MAPbBr₃)_{0.15}-based devices with spiro-OMeTAD, (a) without (20 mg mL⁻¹), and (b) with Li-TFSI and TBP (73 mg mL⁻¹).



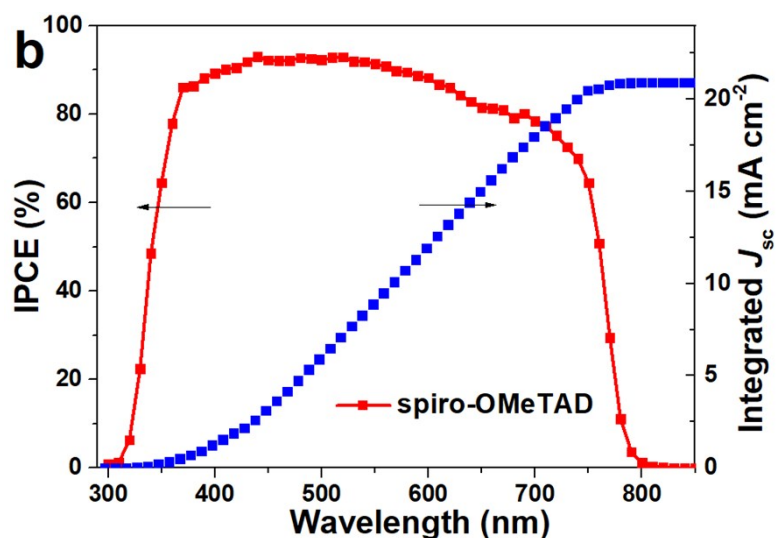


Fig. S6 (a) The incident photon-to-current conversion efficiency (IPCE) integrated J_{sc} spectra of n-i-p $(\text{FAPbI}_3)_{0.85}(\text{MAPbBr}_3)_{0.15}$ -based PSCs with doped **3,6-N** and spiro-OMeTAD.

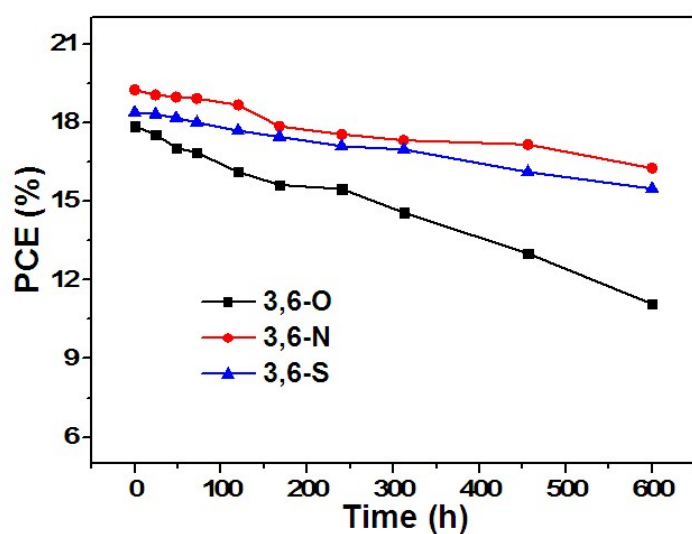


Fig. S7 The stability of the $(\text{FAPbI}_3)_{0.85}(\text{MAPbBr}_3)_{0.15}$ -based devices employing different HTMs without encapsulation under dark and dry condition.

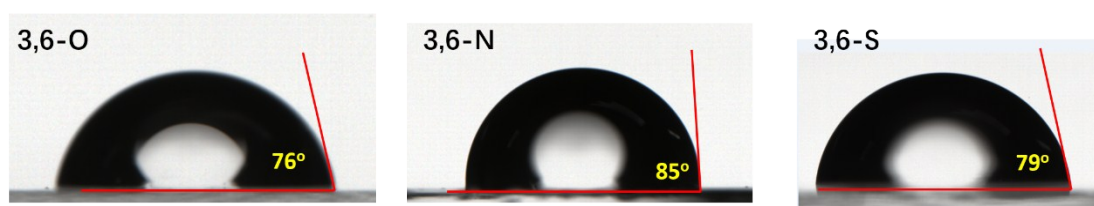


Fig. S8 Water contact angles of **3,6-O**, **3,6-N** and **3,6-O**.

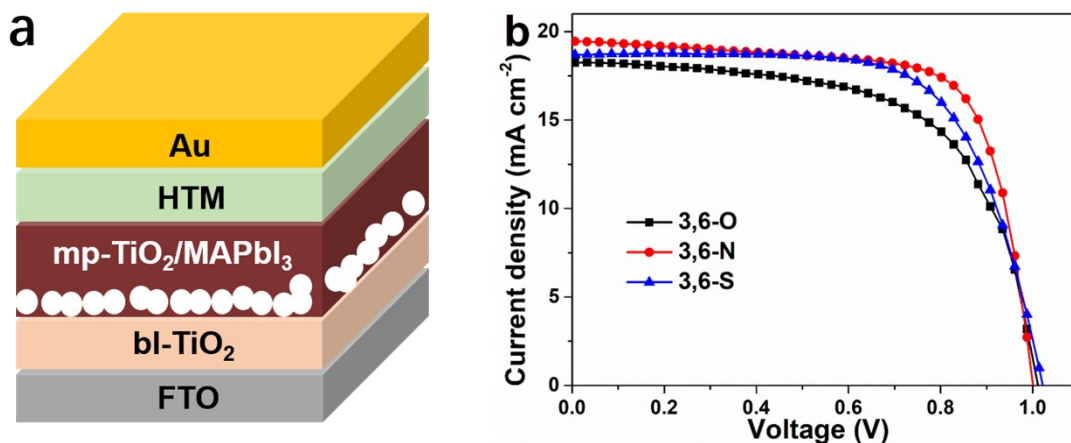


Fig. S9 The structure of n-i-p MAPbI₃-based PSC in this work and corresponding *J-V* curves of best-performing devices employing additive-free HTMs.

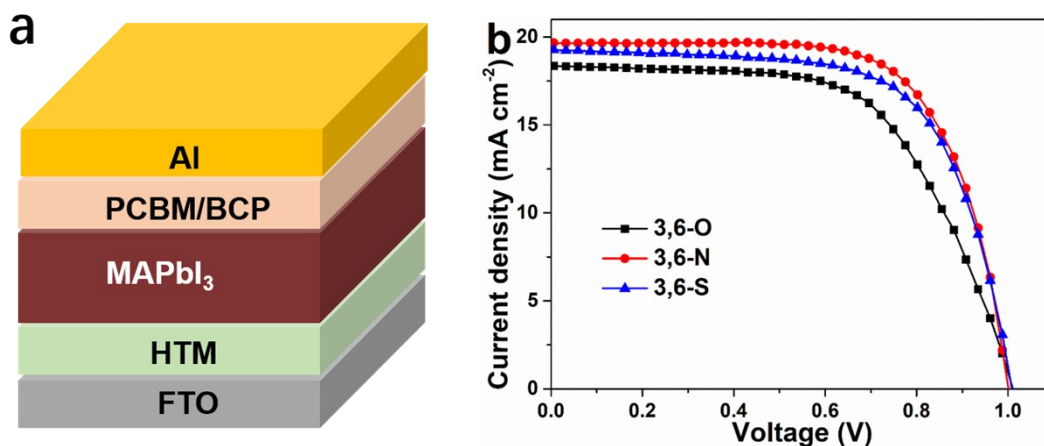


Fig. S10 The structure of p-i-n MAPbI₃-based PSC in this work and corresponding *J-V* curves of best-performing devices employing additive-free HTMs.

Table S5 Photovoltaic parameters of best-performing n-i-p and p-i-n MAPbI₃-based PSCs with pristine HTMs. n-i-p devices: HTM 20 mg mL⁻¹; p-i-n devices: HTM 5 mg mL⁻¹.

1.

Device structure	HTM	V_{oc} (V)	J_{sc} (mA cm ⁻²)	FF (%)	PCE (%)
n-i-p	3,6-O	1.01	18.25	62.42	11.53

	3,6-N	1.00	19.47	72.18	14.05
	3,6-S	1.02	18.54	67.59	12.81
p-i-n	3,6-O	1.01	18.36	60.84	11.29
	3,6-N	1.00	19.52	70.14	13.72
	3,6-S	1.01	19.26	66.33	12.89

Table S6 The average photovoltaic parameters of n-i-p MAPbI₃-based PSCs with different HTMs (without Li-TFSI and TBP).

HTM	Concentratio n (mg mL ⁻¹)	V _{oc} (V)	J _{sc} (mA cm ⁻²)	FF (%)	PCE (%)
3,6-O	10	1.00 ± 0.01	17.26 ± 0.76	60.14 ± 0.84	10.35 ± 0.44
3,6-O	20	1.01 ± 0.01	18.08 ± 0.14	63.10 ± 0.95	11.53 ± 0.22
3,6-O	30	1.00 ± 0.01	17.87 ± 0.39	61.15 ± 0.25	10.93 ± 0.18
3,6-N	10	0.96 ± 0.01	17.82 ± 0.66	66.20 ± 2.54	11.28 ± 0.39
3,6-N	20	0.98 ± 0.01	19.06 ± 0.63	70.95 ± 1.03	13.29 ± 0.69
3,6-N	30	0.90 ± 0.02	16.87 ± 0.52	54.79 ± 0.69	8.27 ± 0.10
3,6-S	10	1.01 ± 0.01	17.46 ± 0.44	62.89 ± 0.70	11.12 ± 0.37
3,6-S	20	1.02 ± 0.01	18.31 ± 0.26	66.64 ± 0.94	12.45 ± 0.28
3,6-S	30	1.01 ± 0.01	17.30 ± 0.22	64.29 ± 0.56	11.24 ± 0.28

Table S7 The average photovoltaic parameters of p-i-n MAPbI₃-based PSCs with different HTMs (without Li-TFSI and TBP).

HTM	Concentratio n (mg mL ⁻¹)	V _{oc} (V)	J _{sc} (mA cm ⁻²)	FF (%)	PCE (%)
3,6-O	5	1.00 ± 0.02	18.14 ± 0.38	60.28 ± 1.16	10.96 ± 0.33

3,6-O	10	0.95 ± 0.01	16.60 ± 0.47	54.87 ± 0.51	8.61 ± 0.16
3,6-N	5	0.98 ± 0.02	19.07 ± 0.32	69.77 ± 1.15	13.05 ± 0.55
3,6-N	10	0.91 ± 0.02	15.74 ± 0.35	65.80 ± 0.64	9.43 ± 0.13
3,6-S	5	1.02 ± 0.02	18.78 ± 0.33	65.72 ± 0.44	12.59 ± 0.22
3,6-S	10	0.96 ± 0.01	17.49 ± 0.22	60.56 ± 0.71	10.16 ± 0.21

Device fabrication

n-i-p MAPbI₃-based PSCs: FTO glass plates were sequentially cleaned by ultrasonic bath, water and ethanol. The compact TiO₂ layer was deposited on the etched substrate by spray pyrolysis at 450 °C using a precursor solution of 0.6 mL titanium diisopropoxide and 0.4 mL bis(acetylacetonate) in 7 mL anhydrous isopropanol. Mesoporous TiO₂ film was deposited on the substrate by spin-coating of a diluted particle TiO₂ paste (Dyesol 30NR-T, 1:5 w/w diluted in ethanol) at 5500 rpm for 20 s. Then the substrates were sintered at 510 °C for 30 min. After cooling down, the perovskite layer was deposited by spin-coating the perovskite precursor solution by a single step procedure. The perovskite precursor solution contained PbI₂ (1.15 M) and MAI (1.1 M), dissolved in a mixed solvent of DMF and DMSO solution (800 μL, volume ratio 1:4). The spin-coating procedure was carried out first 2000 rpm for 10 s, second 5000 rpm for 30 s. 90 μL chlorobenzene was poured on the spinning substrate during the second spin-coating step 15 s before the end of the procedure. The substrate was immediately heated at 100 °C for 1h on a hotplate. The HTM was subsequently deposited on the substrate by spin-coating at 3000 rpm for 20 s. The HTM solution (10-30 mg mL⁻¹) were prepared in anhydrous toluene, which is used without dopants. Finally, a ~60 nm thick Au counter electrode was deposited on top of the film by thermal evaporation. The active area of the device was defined by a black mask with a size of 0.09 cm² for all measurement.

n-i-p (FAPbI₃)_{0.85}(MAPbBr₃)_{0.15}-based PSCs: The mainly fabricated procedures of n-i-p

(FAPbI₃)_{0.85}(MAPbBr₃)_{0.15}-based PSCs is same with n-i-p MAPbI₃-based ones. The difference are as follows. The perovskite precursor solution contained PbBr₂ (0.2 M), MABr (0.2 M), PbI₂ (1.13 M) and FAI (1.1 M) dissolved in a mixed solvent of DMF and DMSO solution (800 μl, volume ratio 1:4). The spin-coating procedure was carried out first 2000 rpm for 10 s, second 5000 rpm for 30 s. 90 μl chlorobenzene was poured on the spinning substrate during the second spin-coating step 15 s before the end of the procedure. The substrate was immediately heated at 100 °C for 1.5 h on a hotplate. The HTM deposited procedure of the devices without dopants was same with n-i-p MAPbI₃-based PSCs. When the HTM is doped, The HTMs were dissolved in anhydrous toluene (45 mg mL⁻¹) with 15 μL of 4-tert-butylpyridine and 8 μL of lithium bis(trifluoromethylsulphonyl)imide (520 mg mL⁻¹ in acetonitrile). The solution is diluted with certain proportion to reduce the concentration.

p-i-n MAPbI₃-based PSCs: The HTMs were prepared on FTO substrates by spin-coating its chlorobenzene (CB) solutions with the concentration of 5 mg mL⁻¹ at the speed of 3000 rpm for 30 s, respectively, and then annealed at 100 °C for 10 min. The stoichiometry perovskite precursor solution (1.2 M, PbI₂ and MAI with a molar ratio of 1:0.98 in mixed-solvent of DMF:DMSO=4:1) was deposited onto the prepared HTL films at 1100 rpm for 10 s and 4200 rpm for 30s. 110 μL chlorobenzene was quickly dripped onto the spinning film at 10 s before the end of the procedure. After that, the deposited films were thermal annealed at 100 °C for 15 min in a nitrogen-filled glove-box. The resulting perovskite films were coated with PC₆₀BM film by spin-coating 20 mg mL⁻¹ PC₆₀BM solution (in CB) at 2000 rpm for 30s, followed by spin-coating the bathocuproine (BCP) solution (0.5 mg mL⁻¹ in isopropanol) at 6000 rpm for 30 s. Finally, the devices were completed by depositing the Ag electrode. The active area of the device was defined by a black mask with a size of 0.1225 cm² for all measurement.

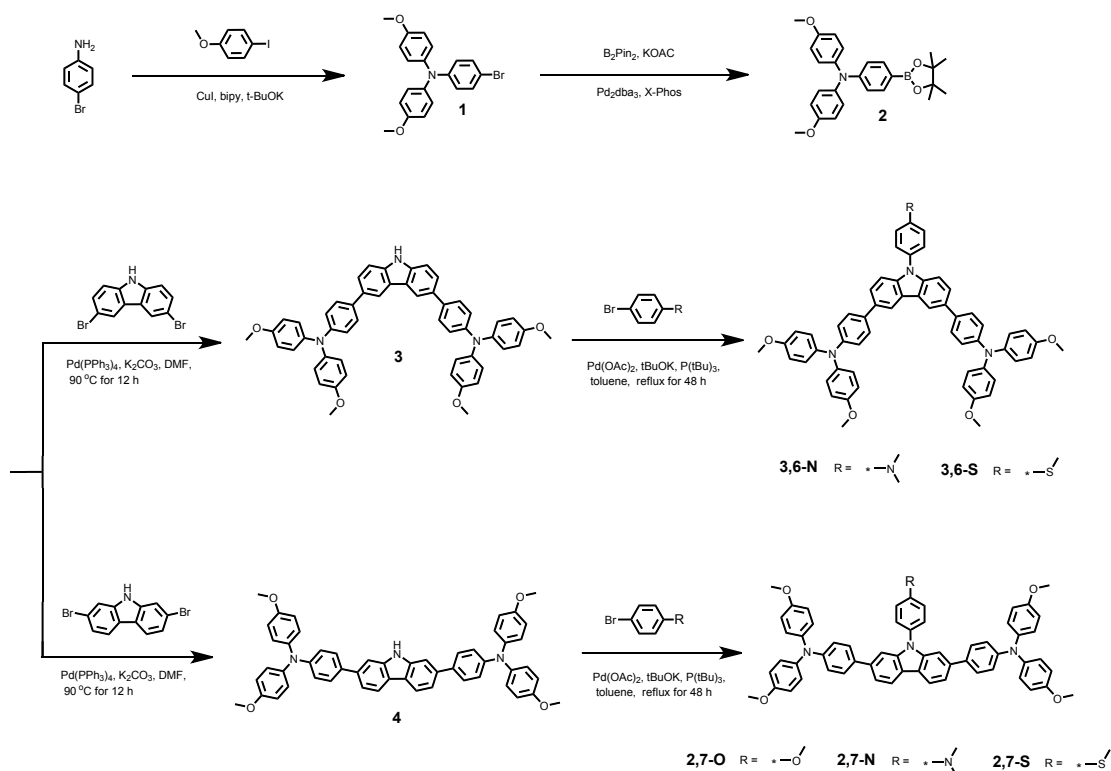
Instrumentation

¹H NMR spectra were carried out on a Brücker spectrometer (400 MHz) with chemical

shifts against tetramethylsilane (TMS). Time-of-flight mass spectrometer (MALDI-TOF-MS) experiments were recorded using a MS Bruker Daltonik Reflex III and Bruker solariX spectrometer. The steady-state photoluminescence measurements were obtained from a Fluorescence Detector (Fluorolog-3, HORIBA, USA) with a standard 450 W xenon CW lamp. Cyclic voltammetry was recorded on a CHI660d electrochemical analyzer (CH Instruments, Inc., China). A normal three electrode system was used consisting of a platinum working electrode, a platinum wire counter electrode, and a calomel reference electrode. Redox potential of them was measured in DCM with 0.1 M tetrabutylammonium hexafluorophosphate with a scan rate of 50 mV s⁻¹ (vs. Fc/Fc⁺ as an external reference). The UV-vis spectra were measured on a U3900H UV-Vis spectrophotometer (Hitachi, Japan). The current-voltage (*J-V*) characteristics of the PSCs were carried out under AM 1.5G (100 mW cm⁻²) illumination that was provided by a 3A grade solar simulator (Newport, USA, 94043A). The incident photon-to-current conversion efficiency (IPCE) was recorded on QE/IPCE measurement kit (Newport, USA). The morphologies of the samples were investigated by atomic force microscopy (5500 AFM (Agilent Technologies)).

Materials and Synthesis of HTMs

All chemicals and reagents were purchased from TCI, Alfa, Sigma-Aldrich or Sinopharm Chemical Reagent Co.. Toluene was dehydrated by 4Å molecular sieves. Other chemicals were used as received with further processing. The final products are synthesized *via* Buchwald-Hartwig and Suzuki-Miyaura cross-coupling reaction, respectively. The detailed synthetic procedures of them are shown as follows.



Scheme S1 Synthetic routes to investigated HTMs in this work. The structures of target HTMs is confirmed by NMR, elemental analysis and HRMS (MALDI-TOF) measurements.

4-bromo-N,N-bis(4-methoxyphenyl)aniline (compound 1)^{1,2}

4-Bromoaniline (3.4 g, 20 mmol), 4-iodoanisole (20 g, 80 mmol), CuI (0.15 g, 0.85 mmol), t-BuOK (6.2 g, 55 mmol), dry 2,2'-bipyridine (0.12 g, 0.85 mmol) were added into a Schlenk flask. Then anhydrous toluene (70 mL) was added to the system and stirred at 120 °C overnight under Ar. The reaction mixture was then cooled down to room temperature and extracted with CH_2Cl_2 , remove the solvent. The crude product was purified by column chromatography (DCM/PE = 2 : 1) to obtain the product as yellow oil (2.64 g, 35%). $^1\text{H NMR}$ (400 MHz, DMSO) δ 7.32 (d, $J = 6.4$ Hz, 2H), 7.05 (d, $J = 6.7$ Hz, 4H), 6.94 (d, $J = 4.3$ Hz, 4H), 6.68 (d, $J = 6.6$ Hz, 2H), 3.75 (s, 6H).

4-methoxy-N-(4-methoxyphenyl)-N-(4-(4,4,5,5-tetramethyl-1,3,2-dioxaborolan-2-yl)phenyl)aniline (compound 2).

Under the protection of Ar, 4-bromoaniline (1.728 g, 3 mmol), bis(pinacolato)diboron

(0.96 g, 3.75 mmol), KOAc (0.9 g, 9.36 mmol), dry 1,4-dioxane were added into a 50 mL flask. Then Pd₂dba₃ (14 mg) and X-Phos (30 mg) were added to the system and stirring at 80 °C overnight. After removing the solvent, the residue mixture was purified by column chromatography (CH₂Cl₂/hexane = 1 : 1) to obtain the white solid (product 2, 1.10 g, 74%). ¹H NMR (400 MHz, DMSO) δ 7.47 (d, 2H), 6.93 (d, 4H), 6.70 (d, 4H), 6.68 (d, 2H), 3.76 (s, 6H), 1.26 (s, 12H). ¹³C NMR (100 MHz, CDCl₃) δ 156.23, 151.44, 140.43, 135.80, 127.20, 119.47, 118.65, 114.77, 83.41, 55.48, 24.89.

Compound 3^{3,4}

3,6-Dibromocarbazole (0.20 g, 0.6 mmol), compound 2 (0.56 g, 1.3 mmol), 2M solution of K₂CO₃ (8 mmol, 1.1 g) in H₂O, [Pd(PPh₃)₄] (0.05 mmol, 60 mg), DMF (20 mL) were added into a 50 mL Ar-protected flask. The reaction solution was kept with stirring at 90 °C for 12 h. After cooling to R.T., the reaction mixture was poured into cold Na₂SO₄ aqueous solution, then the crude product precipitates out as solid. The crude product was purified by column chromatography (CH₂Cl₂/PE = 2:1) to obtain compound 3 as light green solid (0.38 g, 81%). ¹H NMR (400 MHz, DMSO) δ 11.28 (s, 1H), 8.44 (s, 2H), 7.60 (d, *J* = 8.1 Hz, 6H), 7.50 (d, *J* = 6.8 Hz, 2H), 7.05 (d, *J* = 5.6 Hz, 2H), 6.92 (d, *J* = 6.6 Hz, 2H), 3.75 (s, 12H). Anal. Calcd. for C₅₂H₄₃N₃O₄(%): C, 80.70; H, 5.60; N, 5.43. Found: C, 80.69; H, 5.61; N, 5.42.

3,6-N

Compound 1 (0.31 g, 0.4 mmol), 4-bromo-N,N-dimethylaniline (0.1 g, 0.5 mmol), tBuONa (0.58 g, 6 mmol), Pd(OAc)₂ (45 mg, 0.2 mmol) and P(tBu)₃ (0.1 M in toluene, 0.3 mL) were added into a 50 mL flask. Then 15 mL dry toluene was injected in to the flask and degassed using Ar. The reaction solution was kept with stirring at reflux for 48 h. After cooling to R.T., the mixture was diluted by 30 mL CH₂Cl₂ and washed with 50 mL deionized water for 3 times. The organic phase was dried by Na₂SO₄, and removed solvent using rotary evaporator. The crude product was purified by column chromatography (CH₂Cl₂/PE = 3:1) to obtain 3,6-N (0.28 g, 82%). ¹H NMR (400 MHz, DMSO) δ 8.56 (d, 2H), 7.64 (d, 6H), 7.42 (d, 2H), 7.32 (d, 2H), 6.99 (m, 22H), 3.76 (s,

12H), 3.03 (s, 6H). Anal. Calcd. for C₆₀H₅₂N₄O₄ (%) C, 80.69; H, 5.87; N, 6.27. Found: C, 80.68; H, 5.86; N, 6.28. MS (MALDI-TOF) *m/z*: [M⁺] calcd, 892.40; found 892.39.

3,6-S

The product **3,6-S** was prepared following the same procedure to synthesize **3,6-N**. Compound 4-bromothioanisole (0.1 g, 0.5 mmol) was used instead of 4-bromo-N,N-dimethylaniline. The crude product was purified by column chromatography (DCM/PE = 2:1) to obtain **3,6-S**. δ ¹H NMR (400 MHz, DMSO) δ 8.59 (d, 2H), 7.52 (d, 12H), 7.00 (d, 20H), 3.76 (s, 12H), 2.66 (s, 3H). Anal. Calcd. for C₆₀H₅₂N₄O₄ (%) C, 79.08; H, 5.51; N, 4.69; S, 3.58. Found: C, 79.08; H, 5.51; N, 4.68; S, 3.57. MS (MALDI-TOF) *m/z*: [M⁺] calcd, 895.34; found 895.35.

Compound 4^{5,7}

2,7-Dibromocarbazole (0.16 g, 0.5 mmol), compound **2** (0.52 g, 1.2 mmol), 2M solution of K₂CO₃ (8 mmol, 1.1 g) in H₂O, [Pd(PPh₃)₄] (60 mg, 0.05 mmol), DMF (20 mL) were added into a 50 mL Ar-protected flask. The reaction solution was kept with stirring at 90 °C for 12 h. After cooling to R.T., the reaction mixture was poured into cold Na₂SO₄ aqueous solution, then the crude product precipitates out as solid. The crude product was purified by column chromatography (CH₂Cl₂/PE = 1:1) to obtain compound **3** as light green solid (0.31 g, 80%). ¹H NMR (400 MHz, DMSO) δ 8.10 (s, 1H), 7.72 – 7.48 (m, 6H), 7.40 (d, *J* = 7.5 Hz, 2H), 7.17 – 7.01 (m, 8H), 6.91 (dd, *J* = 21.1, 7.5 Hz, 14H), 3.76 (s, 12H). Anal. Calcd. for C₅₂H₄₃N₃O₄(%): C, 80.70; H, 5.60; N, 5.43. Found: C, 80.73; H, 5.58; N, 5.46.

2,7-O

Compound **1** (0.31 g, 0.4 mmol), 4-Iodoanisole (0.12 g, 0.5 mmol), tBuONa (0.58 g, 6 mmol), Pd(OAc)₂ (45 mg, 0.2 mmol) and P(tBu)₃ (0.1 M in toluene, 0.3 mL) were added into a 50 mL flask. Then 15 mL dry toluene was injected in to the flask and degassed using Ar. The reaction solution was kept with stirring at reflux for 48 h. After cooling to R.T., the mixture was diluted by 30 mL CH₂Cl₂ and washed with 50 mL deionized

water for 3 times. The organic phase was dried by Na_2SO_4 , and removed solvent using rotary evaporator. The crude product was purified by column chromatography (DCM/PE = 1:1) to obtain **2,7-O** (0.27g, 78%). ^1H NMR (400 MHz, DMSO) δ 8.26 (d, 2H), 7.61 (d, 2H), 7.58 – 7.44 (m, 6H), 7.38 (d, 2H), 7.31 – 7.17 (m, 4H), 7.15 – 7.02 (m, 8H), 7.01 – 6.87 (m, 8H), 6.85 (d, 2H), 3.89 (s, 3H), 3.75 (s, 12H). Anal. Calcd. for $\text{C}_{59}\text{H}_{49}\text{N}_3\text{O}_5$ (%) C, 80.52; H, 5.61; N, 4.77. Found: C, 80.58; H, 5.60; N, 4.73. MS (MALDI-TOF) m/z : $[\text{M}^+]$ calcd, 879.37; found 879.36.

2,7-N

The product **2,7-N** was prepared following the same procedure to synthesize **2,7-O**. Compound 4-bromo-N,N-dimethylaniline (0.1 g, 0.5 mmol) was used instead of 4-iodoanisole. The crude product was purified by column chromatography (DCM/PE = 2:1) to obtain **2,7-N**. ^1H NMR (400 MHz, CDCl_3) 8.14 (d, 2H), 7.50 (m, 12H), 7.20 – 6.61 (m, 20H), 3.84 (s, 12H), 3.15 (s, 6H). Anal. Calcd. for $\text{C}_{60}\text{H}_{52}\text{N}_4\text{O}_4$ (%) C, 80.69; H, 5.87; N, 6.27. Found: C, 80.68; H, 5.89; N, 6.26. MS (MALDI-TOF) m/z : $[\text{M}^+]$ calcd, 892.40; found 892.42.

2,7-S

The product **2,7-S** was prepared following the same procedure to synthesize **2,7-O**. Compound 4-bromothioanisole (0.1 g, 0.5 mmol) was used instead of 4-iodoanisole. The crude product was purified by column chromatography (DCM/PE = 2:1) to obtain **2,7-S**. ^1H NMR (400 MHz, CDCl_3) δ 8.15 (s, 2H), 7.52 (d, 12H), 7.23 – 6.56 (m, 20H), 3.85 (s, 12H), 2.62 (s, 3H). Anal. Calcd. for $\text{C}_{59}\text{H}_{49}\text{N}_3\text{O}_4\text{S}$ (%) C, 79.08; H, 5.51; N, 4.69; S, 3.58. Found: C, 79.07; H, 5.52; N, 4.67; S, 3.59. MS (MALDI-TOF) m/z : $[\text{M}^+]$ calcd, 895.34; found 895.36.

A simple analysis of relative costs of 3,6-N

We take 3,6-N as a model to analysis the synthesis costs and compare with spiro-OMeTAD. The lab synthesis cost of **3,6-N** are estimated on a model originally proposed

by Osedach *et al.*⁵ Recently, Pertrus and Malinauskas *et al.*⁶⁻⁸ has used the model to estimate the cost of hole transporting materials. For every synthetic step the required amounts of reactants, catalysts, reagents and solvents are calculated to obtain 1 gram of **3,6-N** are reported (Table S3).

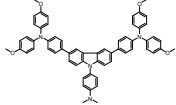
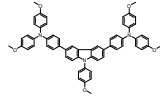
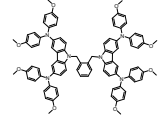
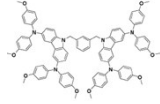
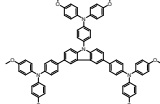
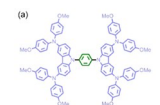
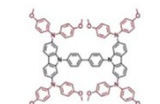
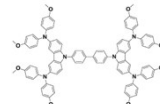
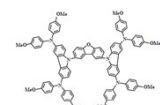
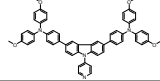
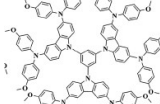
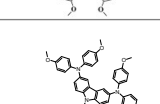
Table S8 Materials, quantities and cost for the synthesis of **3,6-N**.

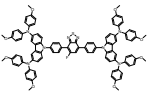
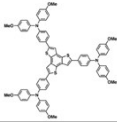
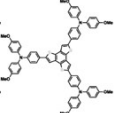
Chemical	Weight Reagent or solvent (g/g)	Price of chemical (\$/g)	Cost of chemical (\$/g product)	Total cost (\$/g)
Compound 1 ^[6]	1.11	19.22	21.33	
4-bromo-N,N- dimethylaniline	0.36	4.31	1.55	
tBuONa	2.07	0.09	0.19	
P(tBu) ₃	0.1	7.01	0.70	
Pd(OAc) ₂	0.16	24.23	3.88	
toluene	50	0.006	0.30	
CH ₂ Cl ₂	450	0.004	1.80	
Petroleum ether	260	0.003	0.78	
3,6-N				30.53

Table S9 Survey of the estimated chemical synthesis cost for different HTMs.

compound	Material cost (\$/g)	Commercial price (\$/g)
3,6-N	30.53	-
Spiro-OMeTAD	91.67 ⁶⁻⁸	170-500 ⁹⁻¹¹

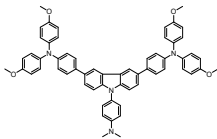
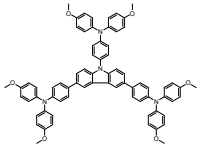
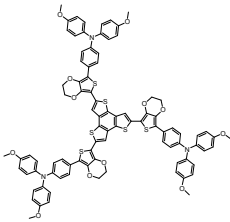
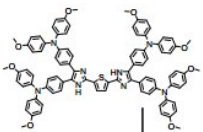


Table S10 The comparison of some reported carbazole-based HTMs and **3,6-N**.

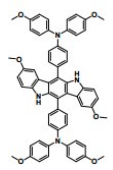
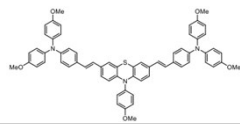
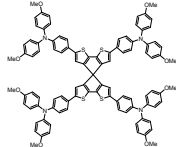
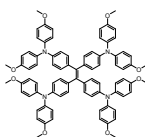
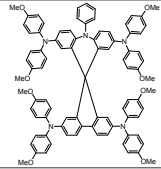
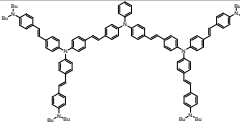
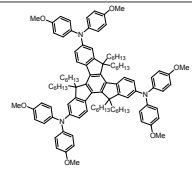
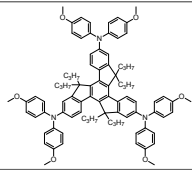
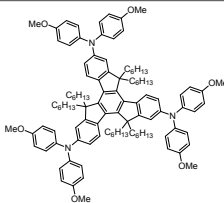
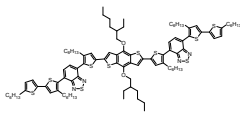
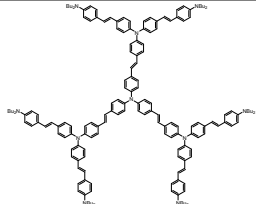
sample	Molecular structures	Device structures	PCE (%) ^[a]	Dopants	Ref. PCE ^[b]	Ref.
3,6-N		FTO/TiO ₂ /(FAPbI ₃) _{0.85} (MAPbBr ₃) _{0.15} /HTM	19.25	TBP, Li-TFSI	19.19	This work
X25		FTO/TiO ₂ /FA _{0.85} MA _{0.15} Pb(I _{0.85} Br _{0.15}) ₃ /HTM	17.40	TBP, Li-TFSI, FK209	-	9
V886		FTO/TiO ₂ /MAPbI ₃ /HTM	16.91	TBP, Li-TFSI, FK209	18.36	10
V885		FTO/TiO ₂ /Cs _{0.1} (MA _{0.15} FA _{0.85}) _{0.9} Pb(I _{0.85} Br _{0.15})/HTM	18.78	TBP, Li-TFSI, FK209	18.41	11
LD29		FTO/TiO ₂ /(FAPbI ₃) _{0.85} (MAPbBr ₃) _{0.15} /HTM	18.09	TBP, Li-TFSI	18.25	4
pPh-2MODP ACz	(a) 	FTO/TiO ₂ /MAPbI ₃ /HTM	19.74	TBP, Li-TFSI	18.60	12
X50		FTO/TiO ₂ /(FAPbI ₃) _{0.85} (MAPbBr ₃) _{0.15} /HTM	19.20	TBP, Li-TFSI	-	13
X19		FTO/TiO ₂ /MAPbI _{3-x} Cl _x /HTM	9.8	TBP, Li-TFSI	10.2	14
BF003		FTO/TiO ₂ /MAPbI ₃ /HTM	14.07	TBP, Li-TFSI, FK209	15.04	15
3,6-Pyr		FTO/TiO ₂ /(FAPbI ₃) _{0.85} (MAPbBr ₃) _{0.15} /HTM	18.45	TBP, Li-TFSI	17.81	16
SGT-405(3,6)		FTO/TiO ₂ /MAPbI _{3-x} Cl _x /HTM	18.87	TBP, Li-TFSI, FK209	17.71	17
dly-2		FTO/TiO ₂ /(FAPbI ₃) _{0.75} (MAPbBr ₃) _{0.17} (MAPbBr ₃) _{0.08} /HTM (planar)	18.23	TBP, Li-TFSI	19.59	18

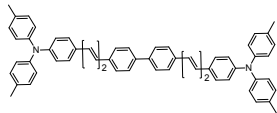
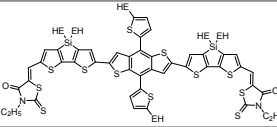
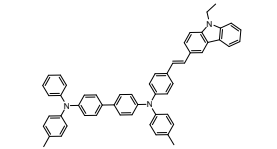
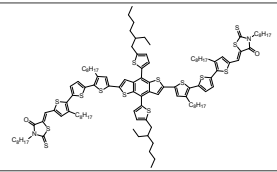
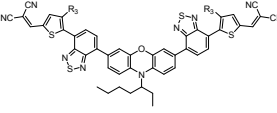
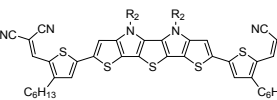
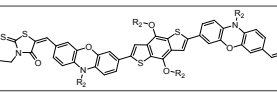
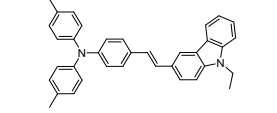
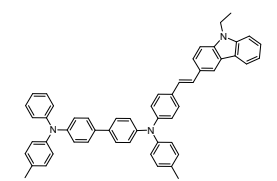
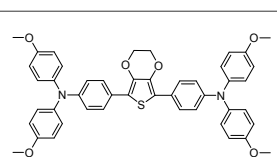
JY6		FTO/TiO ₂ /MAPbI _{3-x} Cl _x /HTM (planar)	18.54	O2	16.21	19
BTT-3		FTO/TiO ₂ /MAPbI ₃ /HTM	18.2	TBP, Li-TFSI, FK209	18.1	20
BTSe-1		FTO/TiO ₂ /(FAPbI ₃) _{0.85} (MAPbBr ₃) _{0.15} /HTM	18.5		18.0	21

[a] The best PCE of developed HTMs; [b] The best PCE of standard doped Spiro-OMeTAD;

Table S11 The comparison of some reported doped-free HTMs and **3,6-N**.

sample	Molecular structures	Device structure	PCE (%) ^[a]	Ref.
3,6-N		FTO/TiO ₂ /(FAPbI ₃) _{0.85} (MAPbBr ₃) _{0.15} /HTM	16.21	This work
LD29		FTO/TiO ₂ /(FAPbI ₃) _{0.85} (MAPbBr ₃) _{0.15} /HTM	14.29	4
YKP03		FTO/TiO ₂ /MAPbI ₃ /HTM	16.15	22
Th-TPA-4A		FTO/TiO ₂ /MAPbI ₃ /HTM	17.5	23
SGT-405(3,6)		FTO/TiO ₂ /MAPbI _{3-x} Cl _x /HTM	8.48	17
pPh-2MODPACz		FTO/TiO ₂ /MAPbI ₃ /HTM	16.09	12

C202		FTO/TiO ₂ /(FAPbI ₃) _{0.85} (MAPbBr ₃) _{0.15} /HTM	17.7	24
AZO-II		ITO/SnO ₂ /Cs _{0.05} MA _{1-y} FA _y PbI _{3-x} Cl _x /HTM	2.50	25
Spiro-CPDT		FTO/TiO ₂ /MAPbI ₃ /HTM	13.4	26
TAE-1		FTO/TiO ₂ /MAPbI ₃ /HTM	11.02	27
SAF-OMe		ITO/TiO ₂ /MAPbI _{3-x} Cl _x /HTM	12.39	28
Z1011		FTO/TiO ₂ /MAPbI ₃ /HTM	16.3	29
Trux 1		ITO/HTM/MAPbI ₃ /PCBM/ZnO/Al	10.2	30
1		FTO/TiO ₂ /MAPbI ₃ /HTM	3.18	31
Trux-OMeTAD		ITO/HTM/MAPbI ₃ /PCBM/ZnO/Al	18.6	32
BDT-C1		FTO/TiO ₂ /MAPbI ₃ /HTM	13.9	33
Z1013		FTO/TiO ₂ /MAPbI ₃ /HTM	15.4	34

2TPA-2-DP		FTO/TiO ₂ /MAPbI ₃ /HTM	12.96	35
DERDTS-TBDT		ITO/TiO ₂ /MAPbI ₃ - xCl _x /HTM/MoO ₃	16.2	36
TPBC		FTO/TiO ₂ /MAPbI ₃ /HTM	13.1	37
DOR3T-TBDT		ITO/TiO ₂ /MAPbI ₃ - xCl _x /HTM/MoO ₃	14.9	38
POZ2		FTO/TiO ₂ /MAPbI ₃ /HTM	12.8	39
oligothiophene 1		FTO/TiO ₂ /MAPbI ₃ /HTM	10.5	40
M1		ITO/ZnO/PC ₇₀ BM/ MAPbI ₃ /HTM	13.2	41
apv-EC		FTO/TiO ₂ /MAPbI ₃ /HTM	12.0	42
TPBC		FTO/TiO ₂ /MAPbI ₃ /HTM	13.3	43
H101		FTO/TiO ₂ /MAPbI ₃ /HTM	11.03	44

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